

# ANTREX Electronics

Electronic Components Sourcing Information

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## Product Reference Information

**Part Number:** FZ500R65KE3C1NPSA1

**Manufacturer:** Infineon Technologies

**Package:** Module

**Availability:** Please confirm with sales

### Product Page:

<https://antrexco.com/product/details/infineon-technologies/fz500r65ke3c1npsa1.html>

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### Note:

This PDF includes an ANTREX product reference cover page.

The original manufacturer datasheet follows from the next page.

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**Highly insulated module with Trench/Fieldstop IGBT3 and emitter controlled 3 diode****Features**

- Electrical features
  - $V_{CES} = 6500\text{ V}$
  - $I_{C\text{ nom}} = 500\text{ A} / I_{CRM} = 1000\text{ A}$
  - Low  $V_{CE,sat}$
- Mechanical features
  - ALSiC base plate for increased thermal cycling capability
  - Extended storage temperature down to  $T_{stg} = -55\text{ °C}$
  - High creepage and clearance distances
  - Package with enhanced insulation of 10.4 kV AC 60 s
  - Package with CTI > 600

**Potential applications**

- Traction drives
- Medium-voltage converters

**Product validation**

- Qualified for industrial applications according to the relevant tests of IEC 60747, 60749 and 60068

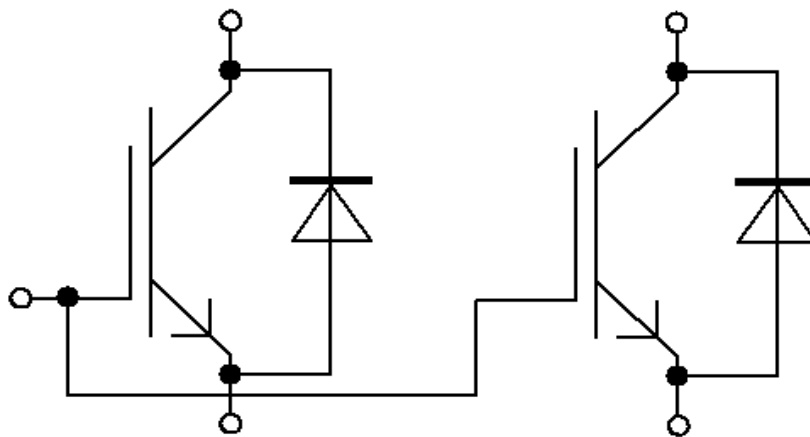
**Description**

Table of contents

|   |                                |    |
|---|--------------------------------|----|
|   | Description .....              | 1  |
|   | Features .....                 | 1  |
|   | Potential applications .....   | 1  |
|   | Product validation .....       | 1  |
|   | Table of contents .....        | 2  |
| 1 | Package .....                  | 3  |
| 2 | IGBT, Inverter .....           | 3  |
| 3 | Diode, Inverter .....          | 5  |
| 4 | Characteristics diagrams ..... | 7  |
| 5 | Circuit diagram .....          | 10 |
| 6 | Package outlines .....         | 11 |
| 7 | Module label code .....        | 12 |
|   | Revision history .....         | 13 |
|   | Disclaimer .....               | 14 |

## 1 Package

**Table 1** Insulation coordination

| Parameter                            | Symbol      | Note or test condition                         | Values | Unit |
|--------------------------------------|-------------|------------------------------------------------|--------|------|
| Isolation test voltage               | $V_{ISOL}$  | RMS, $f = 50 \text{ Hz}$ , $t = 60 \text{ s}$  | 10.4   | kV   |
| Partial discharge extinction voltage | $V_{isol}$  | RMS, $f = 50 \text{ Hz}$ , $Q_{PD}$ typ. 10 pC | 5.1    | kV   |
| DC stability                         | $V_{CE(D)}$ | $T_{vj}=25^{\circ}\text{C}$ , 100 Fit          | 3800   | V    |
| Material of module baseplate         |             |                                                | AlSiC  |      |
| Internal isolation                   |             | basic insulation (class 1, IEC 61140)          | AlN    |      |
| Creepage distance                    | $d_{Creep}$ | terminal to heatsink                           | 64.0   | mm   |
| Creepage distance                    | $d_{Creep}$ | terminal to terminal                           | 56.0   | mm   |
| Clearance                            | $d_{Clear}$ | terminal to heatsink                           | 40.0   | mm   |
| Clearance                            | $d_{Clear}$ | terminal to terminal                           | 26.0   | mm   |
| Comparative tracking index           | $CTI$       |                                                | >600   |      |

**Table 2** Characteristic values

| Parameter                                | Symbol        | Note or test condition                         | Values    |      |      | Unit |
|------------------------------------------|---------------|------------------------------------------------|-----------|------|------|------|
|                                          |               |                                                | Min.      | Typ. | Max. |      |
| Stray inductance module                  | $L_{sCE}$     |                                                |           | 20   |      | nH   |
| Module lead resistance, terminals - chip | $R_{AA'+CC'}$ | $T_C=25^{\circ}\text{C}$ , per switch          |           | 0.18 |      | mΩ   |
| Module lead resistance, terminals - chip | $R_{CC'+EE'}$ | $T_C=25^{\circ}\text{C}$ , per switch          |           | 0.18 |      | mΩ   |
| Storage temperature                      | $T_{stg}$     |                                                | -55       |      | 125  | °C   |
| Mounting torque for module mounting      | $M$           | - Mounting according to valid application note | M6, Screw | 4.25 | 5.75 | Nm   |
| Terminal connection torque               | $M$           | - Mounting according to valid application note | M4, Screw | 1.8  | 2.1  | Nm   |
|                                          |               |                                                | M8, Screw | 8    | 10   |      |
| Weight                                   | $G$           |                                                |           | 1000 |      | g    |

## 2 IGBT, Inverter

**Table 3** Maximum rated values

| Parameter                 | Symbol    | Note or test condition         | Values | Unit |
|---------------------------|-----------|--------------------------------|--------|------|
| Collector-emitter voltage | $V_{CES}$ | $T_{vj} = -50^{\circ}\text{C}$ | 5900   | V    |
|                           |           | $T_{vj} = 25^{\circ}\text{C}$  | 6500   |      |
|                           |           | $T_{vj} = 125^{\circ}\text{C}$ | 6500   |      |

(table continues...)

**Table 3 (continued) Maximum rated values**

| Parameter                         | Symbol    | Note or test condition              |                            | Values   | Unit |
|-----------------------------------|-----------|-------------------------------------|----------------------------|----------|------|
| Continuous DC collector current   | $I_{CDC}$ | $T_{vj\ max} = 150\ ^\circ\text{C}$ | $T_C = 80\ ^\circ\text{C}$ | 500      | A    |
| Repetitive peak collector current | $I_{CRM}$ | $t_P = 1\ \text{ms}$                |                            | 1000     | A    |
| Gate-emitter peak voltage         | $V_{GES}$ |                                     |                            | $\pm 20$ | V    |

**Table 4 Characteristic values**

| Parameter                            | Symbol        | Note or test condition                                                                                                                                                                         |                                | Values |       |      | Unit          |
|--------------------------------------|---------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------|--------|-------|------|---------------|
|                                      |               |                                                                                                                                                                                                |                                | Min.   | Typ.  | Max. |               |
| Collector-emitter saturation voltage | $V_{CE\ sat}$ | $I_C = 500\ \text{A}, V_{GE} = 15\ \text{V}$                                                                                                                                                   | $T_{vj} = 25\ ^\circ\text{C}$  |        | 3.00  | 3.40 | V             |
|                                      |               |                                                                                                                                                                                                | $T_{vj} = 125\ ^\circ\text{C}$ |        | 3.70  | 4.20 |               |
| Gate threshold voltage               | $V_{GEth}$    | $I_C = 70\ \text{mA}, V_{CE} = V_{GE}, T_{vj} = 25\ ^\circ\text{C}$                                                                                                                            |                                | 5.40   | 6     | 6.60 | V             |
| Gate charge                          | $Q_G$         | $V_{GE} = \pm 15\ \text{V}, V_{CE} = 3600\ \text{V}$                                                                                                                                           |                                |        | 20    |      | $\mu\text{C}$ |
| Internal gate resistor               | $R_{Gint}$    | $T_{vj} = 25\ ^\circ\text{C}$                                                                                                                                                                  |                                |        | 1.1   |      | $\Omega$      |
| Input capacitance                    | $C_{ies}$     | $f = 1000\ \text{kHz}, T_{vj} = 25\ ^\circ\text{C}, V_{CE} = 25\ \text{V}, V_{GE} = 0\ \text{V}$                                                                                               |                                |        | 135   |      | nF            |
| Reverse transfer capacitance         | $C_{res}$     | $f = 1000\ \text{kHz}, T_{vj} = 25\ ^\circ\text{C}, V_{CE} = 25\ \text{V}, V_{GE} = 0\ \text{V}$                                                                                               |                                |        | 2.1   |      | nF            |
| Collector-emitter cut-off current    | $I_{CES}$     | $V_{CE} = 6500\ \text{V}, V_{GE} = 0\ \text{V}$                                                                                                                                                | $T_{vj} = 25\ ^\circ\text{C}$  |        |       | 5    | mA            |
| Gate-emitter leakage current         | $I_{GES}$     | $V_{CE} = 0\ \text{V}, V_{GE} = 20\ \text{V}, T_{vj} = 25\ ^\circ\text{C}$                                                                                                                     |                                |        |       | 400  | nA            |
| Turn-on delay time (inductive load)  | $t_{don}$     | $I_C = 500\ \text{A}, V_{CE} = 3600\ \text{V}, V_{GE} = \pm 15\ \text{V}, R_{Gon} = 1.5\ \Omega$                                                                                               | $T_{vj} = 25\ ^\circ\text{C}$  |        | 0.640 |      | $\mu\text{s}$ |
|                                      |               |                                                                                                                                                                                                | $T_{vj} = 125\ ^\circ\text{C}$ |        | 0.650 |      |               |
| Rise time (inductive load)           | $t_r$         | $I_C = 500\ \text{A}, V_{CE} = 3600\ \text{V}, V_{GE} = \pm 15\ \text{V}, R_{Gon} = 1.5\ \Omega$                                                                                               | $T_{vj} = 25\ ^\circ\text{C}$  |        | 0.180 |      | $\mu\text{s}$ |
|                                      |               |                                                                                                                                                                                                | $T_{vj} = 125\ ^\circ\text{C}$ |        | 0.200 |      |               |
| Turn-off delay time (inductive load) | $t_{doff}$    | $I_C = 500\ \text{A}, V_{CE} = 3600\ \text{V}, V_{GE} = \pm 15\ \text{V}, R_{Goff} = 10\ \Omega$                                                                                               | $T_{vj} = 25\ ^\circ\text{C}$  |        | 7.300 |      | $\mu\text{s}$ |
|                                      |               |                                                                                                                                                                                                | $T_{vj} = 125\ ^\circ\text{C}$ |        | 7.600 |      |               |
| Fall time (inductive load)           | $t_f$         | $I_C = 500\ \text{A}, V_{CE} = 3600\ \text{V}, V_{GE} = \pm 15\ \text{V}, R_{Goff} = 10\ \Omega$                                                                                               | $T_{vj} = 25\ ^\circ\text{C}$  |        | 0.400 |      | $\mu\text{s}$ |
|                                      |               |                                                                                                                                                                                                | $T_{vj} = 125\ ^\circ\text{C}$ |        | 0.500 |      |               |
| Turn-on time (resistive load)        | $t_{on\_R}$   | $I_C = 500\ \text{A}, V_{CE} = 2000\ \text{V}, V_{GE} = \pm 15\ \text{V}, R_{Gon} = 1.5\ \Omega$                                                                                               | $T_{vj} = 25\ ^\circ\text{C}$  | 1.62   |       |      | $\mu\text{s}$ |
| Turn-on energy loss per pulse        | $E_{on}$      | $I_C = 500\ \text{A}, V_{CE} = 3600\ \text{V}, L_\sigma = 280\ \text{nH}, V_{GE} = \pm 15\ \text{V}, R_{Gon} = 1.5\ \Omega, di/dt = 2000\ \text{A}/\mu\text{s} (T_{vj} = 125\ ^\circ\text{C})$ | $T_{vj} = 25\ ^\circ\text{C}$  |        | 2800  |      | mJ            |
|                                      |               |                                                                                                                                                                                                | $T_{vj} = 125\ ^\circ\text{C}$ |        | 4300  |      |               |
| Turn-off energy loss per pulse       | $E_{off}$     | $I_C = 500\ \text{A}, V_{CE} = 3600\ \text{V}, L_\sigma = 280\ \text{nH}, V_{GE} = \pm 15\ \text{V}, R_{Goff} = 10\ \Omega, dv/dt = V/\mu\text{s} (T_{vj} = 125\ ^\circ\text{C})$              | $T_{vj} = 25\ ^\circ\text{C}$  |        | 2400  |      | mJ            |
|                                      |               |                                                                                                                                                                                                | $T_{vj} = 125\ ^\circ\text{C}$ |        | 2800  |      |               |

(table continues...)

**Table 4** (continued) **Characteristic values**

| Parameter                              | Symbol              | Note or test condition                                                                                  | Values                                                               |      |      | Unit             |
|----------------------------------------|---------------------|---------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------|------|------|------------------|
|                                        |                     |                                                                                                         | Min.                                                                 | Typ. | Max. |                  |
| SC data                                | $I_{SC}$            | $V_{GE} \leq 15 \text{ V}$ , $V_{CC} = 4500 \text{ V}$ ,<br>$V_{CEmax} = V_{CES} - L_{sCE} \cdot di/dt$ | $t_P \leq 10 \mu\text{s}$ , $T_{vj} \leq 125 \text{ }^\circ\text{C}$ | 3000 |      | A                |
| Thermal resistance, junction to case   | $R_{thJC}$          | per IGBT                                                                                                |                                                                      |      | 13.1 | K/kW             |
| Thermal resistance, case to heat sink  | $R_{thCH}$          | per IGBT, $\lambda_{grease} = 1 \text{ W}/(\text{m}^2\text{K})$                                         |                                                                      | 13.2 |      | K/kW             |
| Temperature under switching conditions | $T_{vj \text{ op}}$ |                                                                                                         | -50                                                                  |      | 125  | $^\circ\text{C}$ |

### 3 Diode, Inverter

**Table 5** **Maximum rated values**

| Parameter                       | Symbol      | Note or test condition                 |                                        | Values | Unit                  |
|---------------------------------|-------------|----------------------------------------|----------------------------------------|--------|-----------------------|
| Repetitive peak reverse voltage | $V_{RRM}$   |                                        | $T_{vj} = -50\text{ }^{\circ}\text{C}$ | 5900   | V                     |
|                                 |             |                                        | $T_{vj} = 25\text{ }^{\circ}\text{C}$  | 6500   |                       |
|                                 |             |                                        | $T_{vj} = 125\text{ }^{\circ}\text{C}$ | 6500   |                       |
| Continuous DC forward current   | $I_F$       |                                        |                                        | 500    | A                     |
| Repetitive peak forward current | $I_{FRM}$   | $t_p = 1\text{ ms}$                    |                                        | 1000   | A                     |
| $I^2t$ - value                  | $I^2t$      | $t_p = 10\text{ ms}, V_R = 0\text{ V}$ | $T_{vj} = 125\text{ }^{\circ}\text{C}$ | 210    | $\text{kA}^2\text{s}$ |
| Maximum power dissipation       | $P_{RQM}$   | $T_{vj} = 125\text{ }^{\circ}\text{C}$ |                                        | 2000   | kW                    |
| Minimum turn-on time            | $t_{onmin}$ |                                        |                                        | 10     | $\mu\text{s}$         |

**Table 6** **Characteristic values**

| Parameter                     | Symbol   | Note or test condition                                                                                                                                           |                                       | Values |      |      | Unit          |
|-------------------------------|----------|------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------|--------|------|------|---------------|
|                               |          |                                                                                                                                                                  |                                       | Min.   | Typ. | Max. |               |
| Forward voltage               | $V_F$    | $I_F = 500 \text{ A}$ , $V_{GE} = 6500 \text{ V}$                                                                                                                | $T_{vj} = 25 \text{ }^\circ\text{C}$  |        | 3.00 | 3.50 | V             |
|                               |          |                                                                                                                                                                  | $T_{vj} = 125 \text{ }^\circ\text{C}$ |        | 2.95 | 3.50 |               |
| Peak reverse recovery current | $I_{RM}$ | $V_R = 3600 \text{ V}$ , $I_F = 500 \text{ A}$ ,<br>$V_{GE} = -15 \text{ V}$ , $-di_F/dt = 2000 \text{ A}/\mu\text{s}$ ( $T_{vj} = 125 \text{ }^\circ\text{C}$ ) | $T_{vj} = 25 \text{ }^\circ\text{C}$  |        | 730  |      | A             |
|                               |          |                                                                                                                                                                  | $T_{vj} = 125 \text{ }^\circ\text{C}$ |        | 800  |      |               |
| Recovered charge              | $Q_r$    | $V_R = 3600 \text{ V}$ , $I_F = 500 \text{ A}$ ,<br>$V_{GE} = -15 \text{ V}$ , $-di_F/dt = 2000 \text{ A}/\mu\text{s}$ ( $T_{vj} = 125 \text{ }^\circ\text{C}$ ) | $T_{vj} = 25 \text{ }^\circ\text{C}$  |        | 570  |      | $\mu\text{C}$ |
|                               |          |                                                                                                                                                                  | $T_{vj} = 125 \text{ }^\circ\text{C}$ |        | 1050 |      |               |

(table continues...)

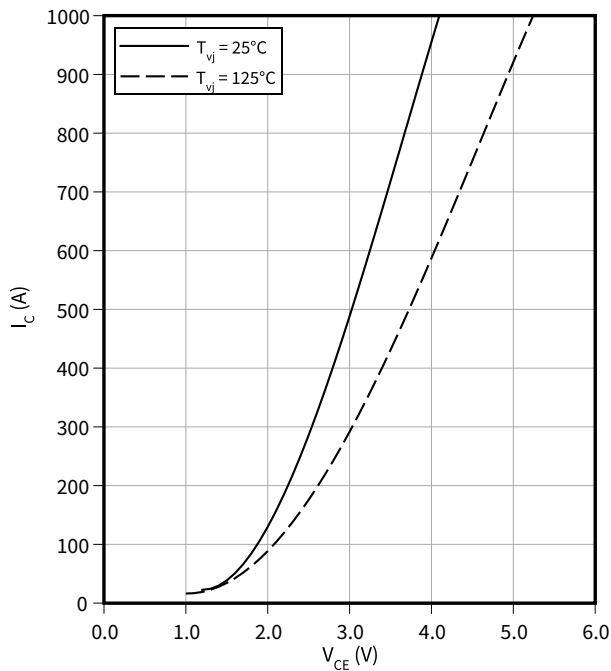
**Table 6** (continued) Characteristic values

| Parameter                              | Symbol             | Note or test condition                                                                                                                          |                          | Values |      |      | Unit |
|----------------------------------------|--------------------|-------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------|--------|------|------|------|
|                                        |                    |                                                                                                                                                 |                          | Min.   | Typ. | Max. |      |
| Reverse recovery energy                | $E_{rec}$          | $V_R = 3600\text{ V}$ , $I_F = 500\text{ A}$ ,<br>$V_{GE} = -15\text{ V}$ , $-di_F/dt = 2000\text{ A}/\mu\text{s}$ ( $T_{vj} = 125\text{ °C}$ ) | $T_{vj} = 25\text{ °C}$  |        | 930  |      | mJ   |
|                                        |                    |                                                                                                                                                 | $T_{vj} = 125\text{ °C}$ |        | 2000 |      |      |
| Thermal resistance, junction to case   | $R_{thJC}$         | per diode                                                                                                                                       |                          |        |      | 27.9 | K/kW |
| Thermal resistance, case to heat sink  | $R_{thCH}$         | per diode, $\lambda_{grease} = 1\text{ W}/(\text{m}^*\text{K})$                                                                                 |                          |        | 21.0 |      | K/kW |
| Temperature under switching conditions | $T_{vj\text{ op}}$ |                                                                                                                                                 |                          | -50    |      | 125  | °C   |

4 Characteristics diagrams

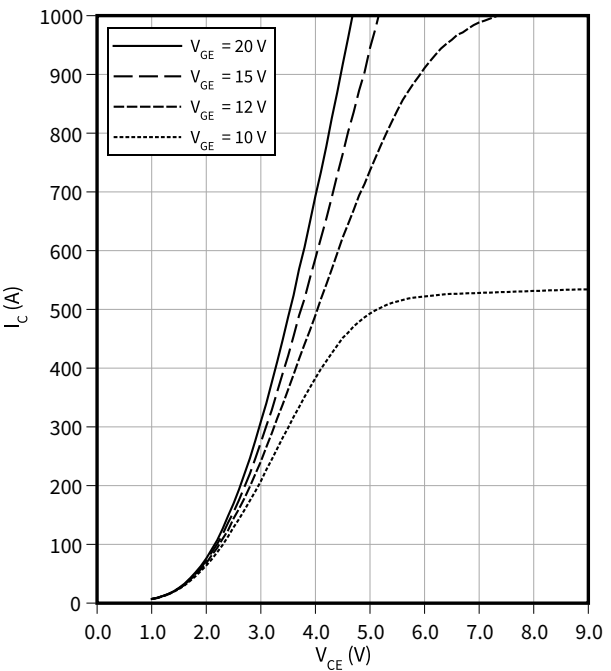
output characteristic (typical), IGBT, Inverter

$I_C = f(V_{CE})$   
 $V_{GE} = 15\text{ V}$



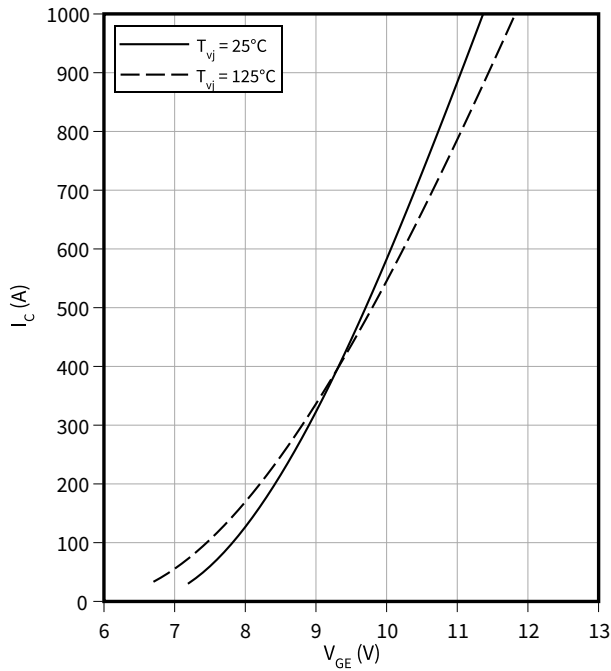
output characteristic (typical), IGBT, Inverter

$I_C = f(V_{CE})$   
 $T_{vj} = 125\text{ °C}$



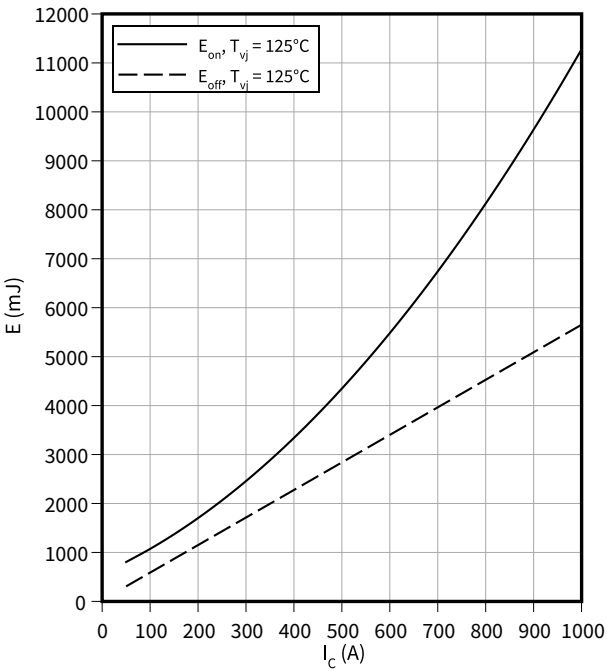
transfer characteristic (typical), IGBT, Inverter

$I_C = f(V_{GE})$   
 $V_{CE} = 20\text{ V}$



switching losses (typical), IGBT, Inverter

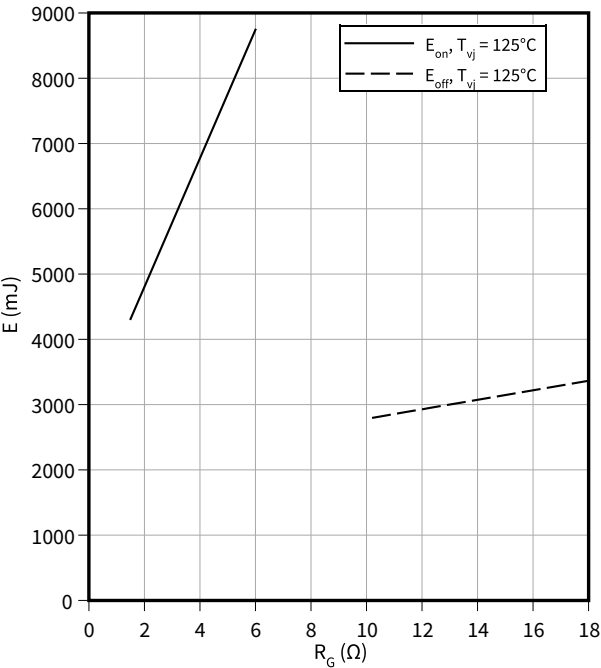
$E = f(I_C)$   
 $R_{Goff} = 10\text{ }\Omega$ ,  $R_{Gon} = 1.5\text{ }\Omega$ ,  $V_{CE} = 3600\text{ V}$ ,  $V_{GE} = \pm 15\text{ V}$



4 Characteristics diagrams

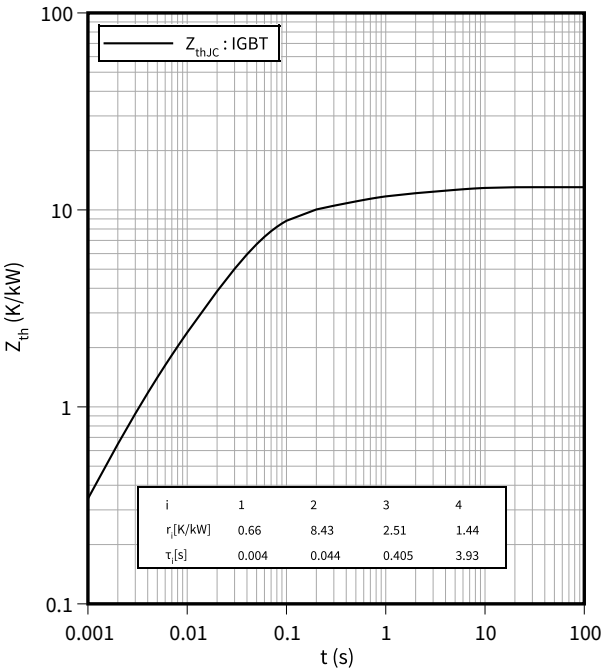
switching losses (typical), IGBT, Inverter

$E = f(R_G)$   
 $I_C = 500\text{ A}$ ,  $V_{CE} = 3600\text{ V}$ ,  $V_{GE} = \pm 15\text{ V}$



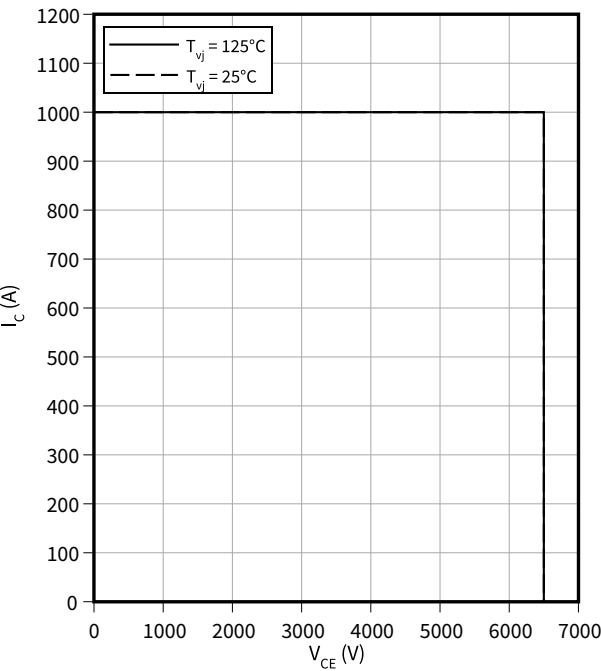
transient thermal impedance , IGBT, Inverter

$Z_{th} = f(t)$



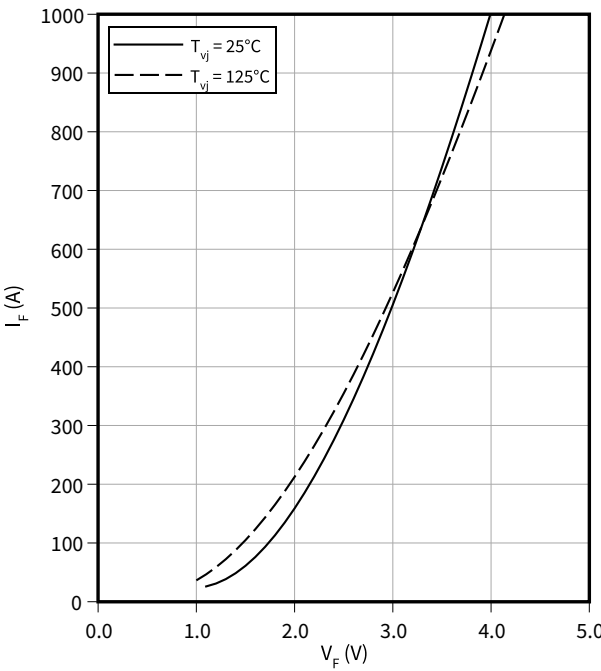
reverse bias safe operating area (RBSOA), IGBT, Inverter

$I_C = f(V_{CE})$   
 $R_{Goff} = 10\ \Omega$ ,  $V_{GE} = \pm 15\text{ V}$ ,  $T_{vj} = 125\text{ }^\circ\text{C}$



forward characteristic of (typical), Diode, Inverter

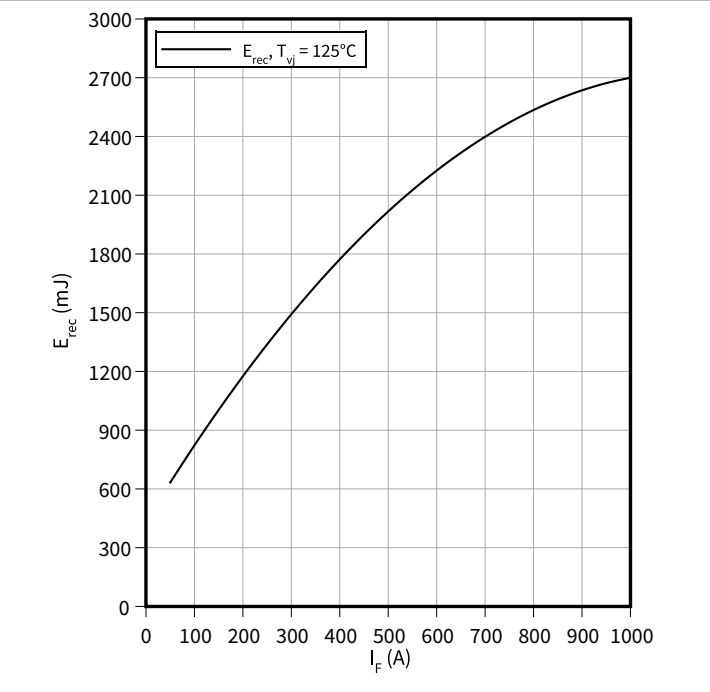
$I_F = f(V_F)$



4 Characteristics diagrams

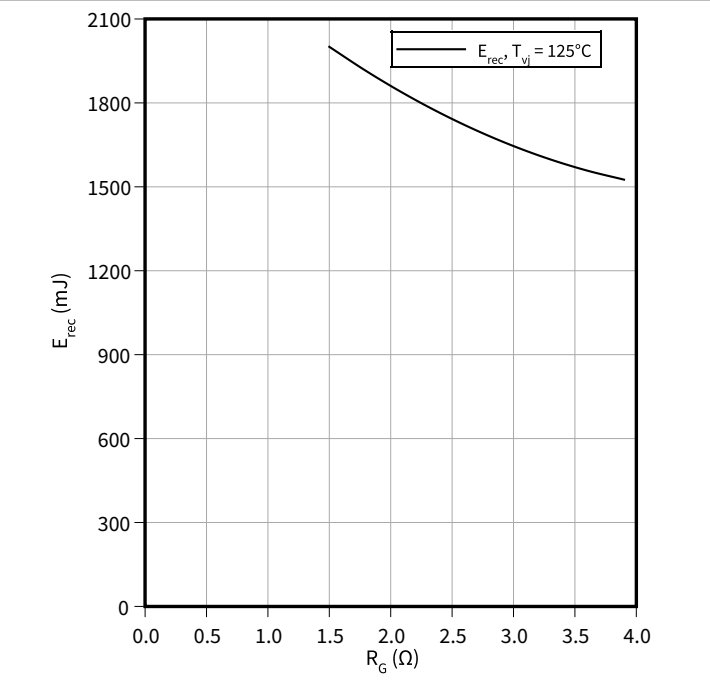
switching losses (typical), Diode, Inverter

$E_{rec} = f(I_F)$   
 $V_{CE} = 3600\text{ V}, R_{Gon} = R_{Gon}(IGBT)$



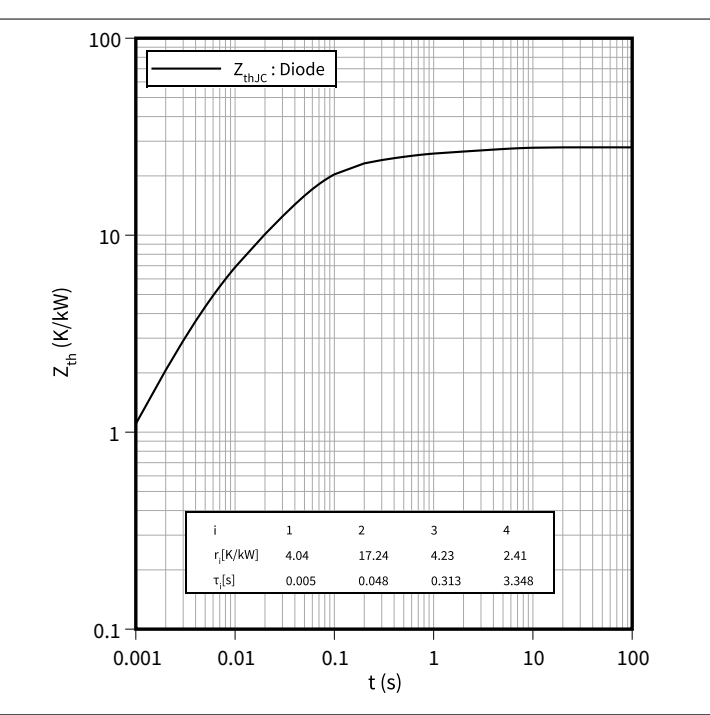
switching losses (typical), Diode, Inverter

$E_{rec} = f(R_G)$   
 $V_{CE} = 3600\text{ V}, I_F = 500\text{ A}$



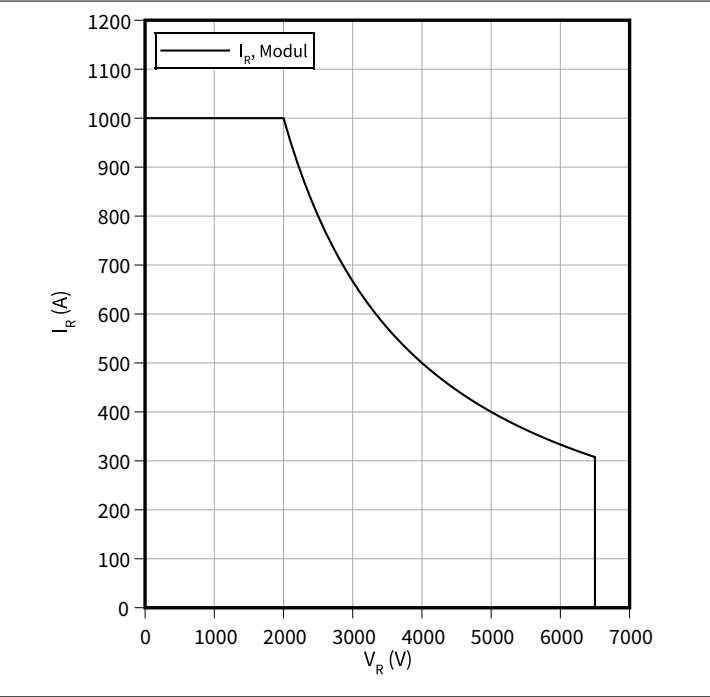
transient thermal impedance , Diode, Inverter

$Z_{th} = f(t)$



safe operation area (SOA), Diode, Inverter

$I_R = f(V_R)$   
 $T_{vj} = 125\text{ °C}$



5      Circuit diagram

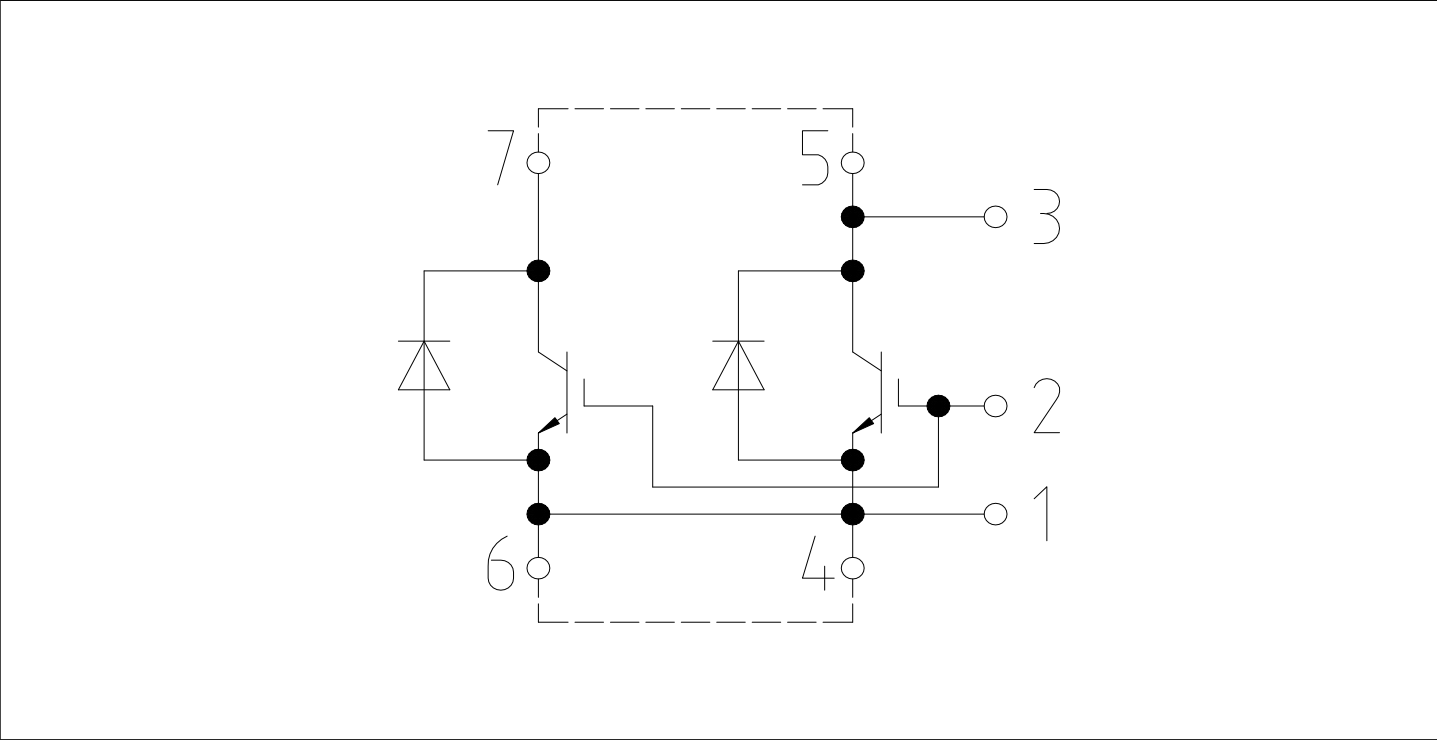
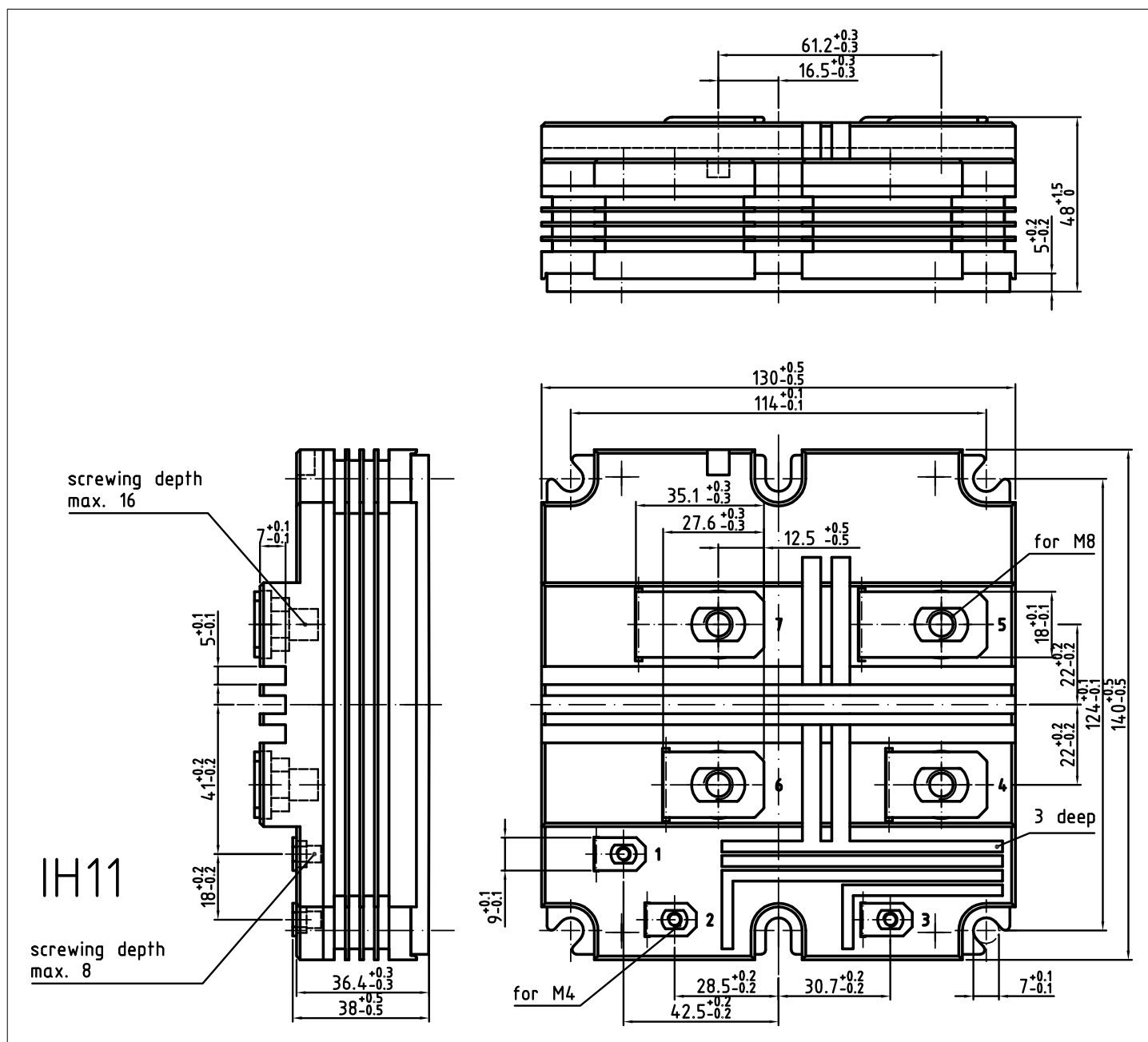


Figure 1



### Figure 2

7 Module label code

| Module label code |                                                                                                                                                                                                                                            |         |                 |
|-------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------|-----------------|
| Code format       | Data Matrix                                                                                                                                                                                                                                |         | Barcode Code128 |
| Encoding          | ASCII text                                                                                                                                                                                                                                 |         | Code Set A      |
| Symbol size       | 16x16                                                                                                                                                                                                                                      |         | 23 digits       |
| Standard          | IEC24720 and IEC16022                                                                                                                                                                                                                      |         | IEC8859-1       |
| Code content      | Content                                                                                                                                                                                                                                    | Digit   | Example         |
|                   | Module serial number                                                                                                                                                                                                                       | 1 – 5   | 71549           |
|                   | Module material number                                                                                                                                                                                                                     | 6 - 11  | 142846          |
|                   | Production order number                                                                                                                                                                                                                    | 12 - 19 | 55054991        |
|                   | Date code (production year)                                                                                                                                                                                                                | 20 – 21 | 15              |
|                   | Date code (production week)                                                                                                                                                                                                                | 22 – 23 | 30              |
| Example           | <div></div> <div>7154914284655054991153071549142846550549911530</div> |         |                 |

Figure 3

## Revision history

| Document revision | Date of release | Description of changes                                                                                                                              |
|-------------------|-----------------|-----------------------------------------------------------------------------------------------------------------------------------------------------|
| V1.0              | 2009-04-06      | Target datasheet                                                                                                                                    |
| V2.0              | 2010-12-13      | Preliminary datasheet                                                                                                                               |
| V2.1              | 2012-06-25      | Preliminary datasheet                                                                                                                               |
| V2.2              | 2012-08-22      | Preliminary datasheet                                                                                                                               |
| V3.0              | 2014-06-16      | Final datasheet                                                                                                                                     |
| V3.1              | 2018-01-15      | Final datasheet                                                                                                                                     |
| V3.2              | 2019-09-06      | Final datasheet                                                                                                                                     |
| V3.3              | 2020-05-06      | Final datasheet                                                                                                                                     |
| n/a               | 2020-09-01      | Datasheet migrated to a new system with a new layout and new revision number schema: target or preliminary datasheet = 0.xy; final datasheet = 1.xy |
| 1.10              | 2021-10-25      | Final datasheet                                                                                                                                     |

## Trademarks

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**Email: [erratum@infineon.com](mailto:erratum@infineon.com)**

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